TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

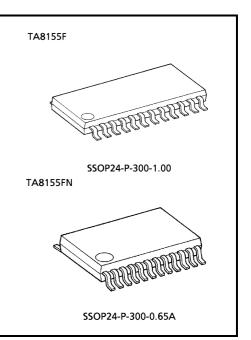
# TA8155F,TA8155FN

REC / PB System Dual Pre-amplifier (1.5 / 3V USE)

The TA8155F and TA8155FN are REC / PB system dual pre amplifier ICs, which are developed for low voltage operation (1.5 / 3V use). These are especially suitable for a stereo headphone cassette player.

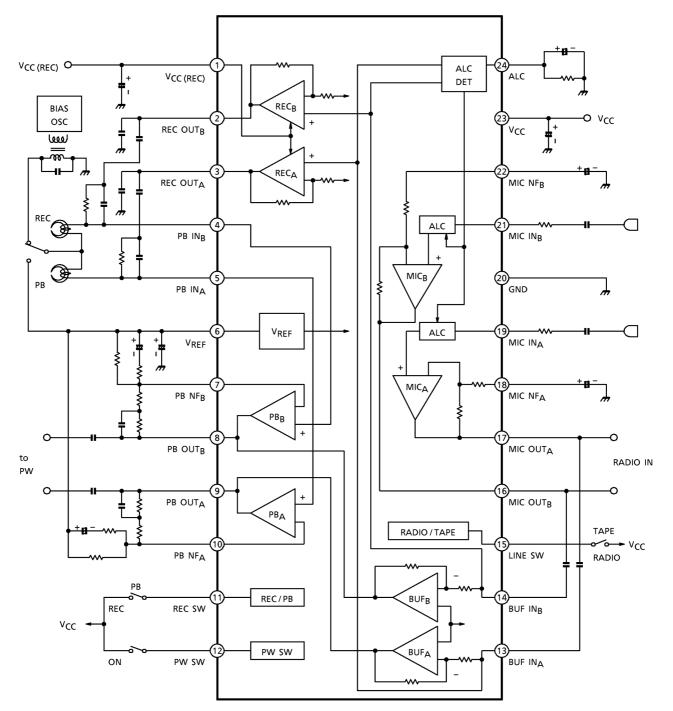
#### Features

- Built-in dual playback amplifiers. Input coupling condenser-less. Built-in capacitor for buzz noise.
- Built-in dual buffer amplifiers. For radio signal inut. Monitor for REC mode.
- Built-in dual microphone amplifiers.
  Built-in an ALC circuit for MIC-REC mode.
  Attack time. : 0.1s (typ.)
  Recovery time. : 3.5s (typ.)
- Built-in dual recording amplifiers. Single-end output type.
- Built-in a power switch.
- Low power dissipation.
  PB mode : 2.9mW (typ.)
  MIC-REC mode : 8.9mW (typ.)
- Operating supply voltage range. (Ta = 25°C)
  VCC (opr) = 0.9~4V
  VCC (opr) (REC) = 1.8~4V



Weigh SSOP24-P-300-1.00: 0.32g (typ.) SSOP24-P-300-0.65A: 0.14g (typ.)

#### **Block Diagram**



**Terminal Explanation** Terminal Voltage : Typical Terminal Voltage at no Signal with Test Circuit.

$(V_{CC} = 1)$	.2V, V <sub>CC (REC)</sub>	= 2.4V, Ta = 25°C)
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	Terminal	Function	Internal Circuit	Terminal
No.	Name	i uncuori		Voltage (V)
1	V <sub>CC(REC)</sub>	This terminal voltage supplies output stage of recording amplifier with power source.		2.4
2	REC OUT <sub>B</sub>	Output of recording amplifier.		1.15
3	REC OUT <sub>A</sub>			1.10
4	PB IN <sub>B</sub>	Input of playback amplifier.		0.85
5	PB IN <sub>A</sub>			
7	PB NF <sub>B</sub>	NF of playback amplifier.		0.85
10	PB NF <sub>A</sub>			0.00
6	V <sub>REF</sub>	Reference voltage. All amplifier operate on this voltage.	V <sub>CC</sub>	0.85
8	PB OUT <sub>B</sub>	Output of playback amplifier		0.55
9	PB OUT <sub>A</sub>	and buffer amplifier.		
11	REC SW	REC / PB switch. V <sub>CC</sub> : REC mode. GND / OPEN: PB mode.		_
12	PW SW	Power switch. V <sub>CC</sub> : Power on. GND / OPEN: Power off.		_
15	Line SW	Line switch. VCC: BUF (radio) mode. GND / OPEN: Tape mode.		_

	Terminal	Function	Internal Circuit	Terminal
No.	Name			Voltage (V)
13	BUF IN <sub>A</sub>	Input of buffer amplifier and recording amplifier. (Buffer amplifier is inverter type.)	40kΩ BUF C S VREF PB REC 9	0.85
14	BUF IN <sub>B</sub>	ALC level of microphone amplifier is determined by signal level of this terminal	20kΩ 20kΩ 1.5kΩ VREF ALC DET	0.00
16	MIC OUT <sub>B</sub>	Output of microphone	90kΩ 3.9kΩ 17	0.55
17	MIC OUT <sub>A</sub>	amplifier.		
18	MIC NF <sub>A</sub>	NF of microphone amplifier.		0.05
22	MIC NF <sub>B</sub>			
19	MIC IN <sub>A</sub>	Input of microphone amplifier. Built–in capacitor for buzz		0.01
21	MIC IN <sub>B</sub>	noise.	$m = \frac{1.1 k\Omega}{9.5 k\Omega} m$	
20	GND	—	_	0
23	V <sub>CC</sub>	—	_	1.2
24	ALC	ALC terminal. ALC function is operated in only MIC–REC mode.		0.11

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#### **Application Note**

#### (1) PW SW

It is necessary to connect an external pull-down resistor with the terminal PW SW (pin(12)), in case that this IC is turned on due to external noise etc.

#### (2) Mode SW

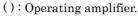
IC mode is determined by switch condition of RED SW (pin(11)) and LINE SW (pin(15))

(Table.1)

H level: Bias current should be applied to switch terminal more than  $5\mu A.$ 

L level: Bias voltage should be applied to switch terminal from 0V to 0.3V.

Table.1 IC mode								
REC SW LINE SW	L	н						
L	PB mode (PB)	MIC-REC (BUF,MIC,REC)						
Н	Radio mode (BUF)	Radio-REC mode (BUF,REC)						



The leak current flows through the terminal of REC SW (pin(11)) or LINE SW (pin(15)), in case that the terminals connected with V<sub>CC</sub> line independently, even though this IC is off-mode (the terminal of PW SW (pin(12)) is off-mode).

And it is necessary to connect an external pull-down resistor with the terminal REC SW (pin(11)) and LINE SW (pin(15)), in case that this IC is turned on due to external noise etc.

#### (3) Playback amplifier

Output voltage of playback amplifier is determined by an external resistor  $\mathrm{R}_1$  and  $\mathrm{R}_f$ .

$$V_{O} (PRE) = V_{REF} - \Delta V - R_{f} (\frac{\Delta V}{R_{1}} - I_{B(NF)})$$

 $\Delta V$  is an off–set voltage which is designed to 18mV.

In case that  $\beta$  of transistor is assumed 100,  $I_{B(NF)}$  is flowed 0.2µA in Fig.1. And output voltage of playback amplifier (pin (8),(9)) in Fig.1 is

 $V_{O}$  (PRE) = 0.85V-0.018V- (330k $\Omega$ +13k $\Omega$ )

$$x \left(\frac{0.018V}{18k\Omega} - 0.2\mu A\right) = 0.56(V)$$

Output voltage of playback amplifier should be fixed V<sub>CC</sub> / 2, because playback amplifier get a enough dynamic range. And current source of  $20\mu$ A is operated except playback mode, in order to reduce a pop sound in swichover between playback on / off mode (Fig.2).

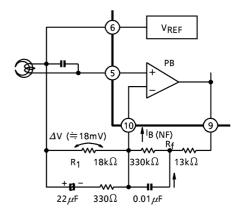


Fig.1 DC output voltage of playback amplifier.

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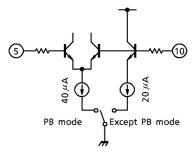
#### (4) Microphone amplifier

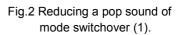
Current source of  $5.5\mu$ A is operated except MIC–REC mode, because bias is applied to the same output voltage as output voltage of microphone amplifier in operation (Fig.3).

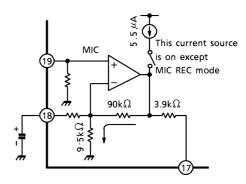
#### (5) VCC (REC)

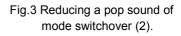
The VCC (REC) terminal (pin(1)) is applied bias to VCC (REC) = VCC-0.7V, because the VCC (REC) terminal (pin(1)) is connected with the VCC terminal (pin(23)) by diode, as internal circuit of termial explanation.

And supply current doesn't flow through VCC (REC) terminal (pin(1)), in case that the terminal is connectd with VCC line, even though this IC is on-mode and except REC mode.









#### Maximum Ratings (Ta = 25°C)

Characte	ristic	Symbol	Rating	Unit	
Supply voltage		V <sub>CC</sub>	4.5	V	
Supply voltage		V <sub>CC (REC)</sub>	4.5	v	
Power dissipation	TA8155F	P <sub>D</sub> (Note)	400	mW	
rower dissipation	TA8155FN		500		
Operating Temperatu	re	T <sub>opr</sub>	-25~75	°C	
Storage temperature		T <sub>stg</sub>	-55~150	°C	

(Note) Derated above Ta = 25°C in the proportion of 3.2mW / °C for TA8155F, and of 4mW / °C for TA8155FN.

#### **Electrical Characteristics**

Unless Otherwise Specified:  $V_{CC} = 1.2V$ ,  $V_{CC(REC)} = 2.4V$ , f = 1kHz, Ta = 25°C, SW<sub>1</sub>: a, SW<sub>8</sub>: OPEN, SW<sub>9</sub>: ON, SW<sub>10</sub>: ON, SW<sub>11</sub>: ON, SW<sub>2</sub>~SW<sub>7</sub> condition

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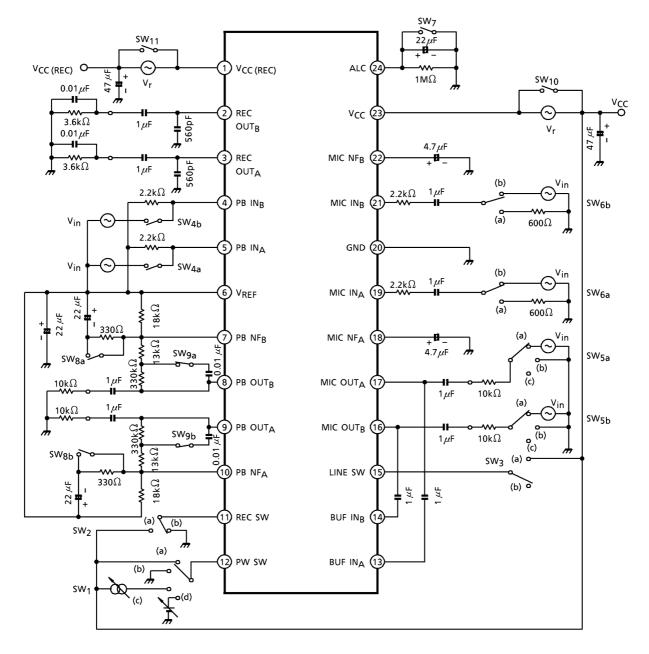
Characteristic		Symbol	Test Cir- cuit	Test Condition	Min.	Тур.	Max.	Unit	
	PW off		I <sub>CCQ1</sub>		$SW_1$ : b, $SW_2$ : b, $SW_3$ : b	_	0.1	5	μA
РВ		I <sub>CCQ2</sub>		SW <sub>2</sub> : b, SW <sub>3</sub> : b	_	2.6	3.9		
Quies	Quiescent Radio		I <sub>CCQ3</sub>		SW <sub>2</sub> : b, SW <sub>3</sub> : a	_	2.4	3.6	
curren	ıt	Radio-REC	I <sub>CCQ4</sub>		SW <sub>2</sub> : a, SW <sub>3</sub> : a	_	3.0	4.5	mA
		MIC-REC	I <sub>CCQ5</sub>		SW <sub>2</sub> : a, SW <sub>3</sub> : b	_	4.5	6.5	
		V <sub>CC (REC)</sub>	I <sub>CCQ6</sub>		SW <sub>2</sub> : a, SW <sub>3</sub> : b	1.3	1.5	2.4	
Refere	ence voltage		V <sub>REF</sub>	_		0.8	0.85	0.9	V
	Open loop vo gain	oltage	G <sub>VO</sub>	_	SW8: ON, SW9: OPEN V <sub>o</sub> = -17dBV	58	70	_	dB
	Closed loop v gain	voltage	G <sub>VC</sub>	_	V <sub>o</sub> = -17dBV	_	36	_	üБ
plifier	Maximum ou voltage	tput	V <sub>om1</sub>	_	THD = 1%	200	310	—	mV <sub>rms</sub>
Playback amplifier	Total harmon distortion	lic	THD1	-	V <sub>o</sub> = -17dBV	-	0.1	0.3	%
Playb	Equivalent input noise voltage		V <sub>ni</sub>	_	SW <sub>4</sub> : OPEN BPF = 30Hz~20kHz NAB (G <sub>V</sub> = 36dB,f = 1kHz)	_	1.2	3.0	μV <sub>rms</sub>
	Cross talk (CH–A / CH–B)		CT1	—	V <sub>o</sub> = -17dBV	_	62	_	
	Ripple rejection ratio		RR1	-	SW <sub>4</sub> : OPEN, SW <sub>10</sub> : OPEN $f_r = 100Hz$ , $V_r = -32dBV$	-	40	_	dB
	Voltage gain		G <sub>V2</sub>	_	$V_0 = -17 dBV$	-4	-2	0	dB
er	Maximum output voltage		V <sub>om2</sub>	_	THD = 1%	200	270	_	mV <sub>rms</sub>
Buffer amplifier	Total harmonic distortion		THD2	_	V <sub>o</sub> = –17dBV	_	0.1	_	%
uffer	Output noise	voltage	V <sub>no2</sub>	_	SW <sub>5</sub> : b, BPF = 30Hz~20kHz	_	35	_	μV <sub>rms</sub>
ы	Cross talk (C	H–A / CH–B)	CT2	—	V <sub>o</sub> = -17dBV	_	51	-	
	Ripple rejecti	on ratio	RR2	-	SW <sub>5</sub> : b, SW <sub>10</sub> : OPEN f <sub>r</sub> = 100Hz,V <sub>r</sub> = -32dBV	-	55	_	dB
	Voltage gain		G <sub>V3</sub>	_	$V_0 = -12 dBV$	16.5	18.5	20.5	dB
	Maximum output voltage		V <sub>om3</sub>	_	THD = 1%	500	720	_	mV <sub>rms</sub>
Recording amplifier	Total harmon distortion	Fotal harmonic  THD3  —  V <sub>o</sub> = -12dBV		V <sub>o</sub> = -12dBV	_	0.1	0.5	%	
Rec	Output noise	voltage	V <sub>no3</sub>	_	SW <sub>5</sub> : b, BPF = 30Hz~20kHz	:Hz — 0.09 0.25		0.25	mV <sub>rms</sub>
	Cross talk (C	H–A / CH–B)	CT3	_	$V_0 = -12$ dBV	_	49	_	
	Ripple rejecti	on ratio	RR3	_	SW <sub>5</sub> : b, SW <sub>10</sub> : OPEN f <sub>r</sub> = 100Hz, V <sub>r</sub> = -32dBV	_	40	_	dB

	Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
	Voltage gain		G <sub>V4</sub>	_	V <sub>o</sub> = -17dBV	30	32.5	35	dB
	Maximum ou voltage	tput	V <sub>om4</sub>	—	THD = 1%	120	200	_	mV <sub>rms</sub>
Microphone amplifier	Total harmor distortion	nic	THD4	_	V <sub>o</sub> = -17dBV	_	0.25	0.8	%
Micro	Output noise	voltage	V <sub>no4</sub>	_	SW <sub>6</sub> : a, BPF = 30Hz~20kHz	_	0.12	_	mV <sub>rms</sub>
	Cross talk (C	H–A / CH–B)	CT4	_	V <sub>o</sub> = -17dBV	_	52	—	
	Ripple rejecti	on ratio	RR4	_	SW <sub>6</sub> : a, SW <sub>10</sub> : OPEN f <sub>r</sub> = 100Hz,V <sub>r</sub> = -32dBV	_	36	_	dB
	Voltage gain		G <sub>V5</sub>	_	SW <sub>7</sub> : ON, V <sub>0</sub> = -17dBV	_	58	_	dB
	Maximum output voltage		V <sub>om5</sub>	_	THD = 3%	600	800	_	mV <sub>rms</sub>
+	ALC total harmonic distortion		THD5	_	V <sub>in</sub> = -32dBV	_	0.8	_	%
ifier ifier	Output noise	voltage	V <sub>no5</sub>	_	SW <sub>6</sub> : a, BPF = 30Hz~20kHz	-	2.1	3.5	mV <sub>rms</sub>
Microphone amplifier recording amplifier	ALC voltage		V <sub>oALC1</sub>	_	– V <sub>in</sub> = –62dBV		-8.5	-6.7	dBV
one	ALO VOltage		V <sub>oALC2</sub>		V <sub>in</sub> = -32dBV	-11.7	-8.5	-6.7	ub v
crophone recording	ALC channel	balance	CB <sub>ALC</sub>		v <sub>In</sub> - 3200 v	—	0	1.5	
Mic	ALC width		W <sub>ALC</sub>	_	$V_{oALC} \le 3dB$ (input voltage) with respect to standard $V_{in} = -42dBV$	_	48	_	dB
	Cross talk (C	Cross talk (CH–A / CH–B)		_	V <sub>in</sub> = -32dBV	_	37	_	
	Ripple rejection ratio		RR5	_	SW <sub>6</sub> : a, f <sub>r</sub> = 100Hz, V <sub>r</sub> = -17dBV	_	39	_	dB
Power	Power on current		I <sub>12</sub>	_	$SW_1$ : c, $SW_2$ : b, $SW_3$ : b $V_6 \ge 0.6V$	5	—	_	μA
	SWIGH	Power off voltage	V <sub>12</sub>	_	$SW_1$ : d, $SW_2$ : b, $SW_3$ : b $V_6 \leq 0.2V$	0	_	0.3	V

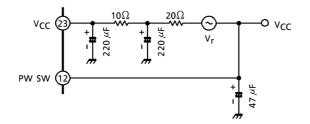
#### Switch Condition For Test Mode (unless otherwise specified.)

Mode	PB AMP. (PB mode)	BUF AMP. (radio mode)	REC AMP. (radio–REC mode)	MIC AMP. MIC AMP. + REC A (MIC mode) (MIC-REC mode		
Operating Amplifier Switch	PB	BUF	BUF REC	MIC-ALC BUF, REC		
SW <sub>2</sub>	b	b	а	а		
SW3	b	а	а	b		
SW4	ON	OPEN	OPEN	OPEN		
SW5	b	а	а	b c		
SW <sub>6</sub>	а	а	а	b		
SW7	OPEN	OPEN	OPEN	ON	OPEN	

#### **Test Circuit**

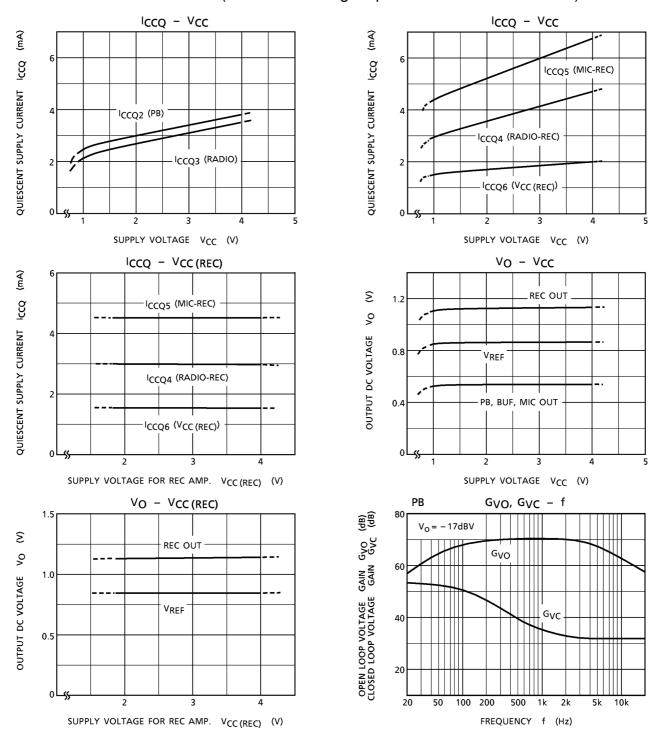


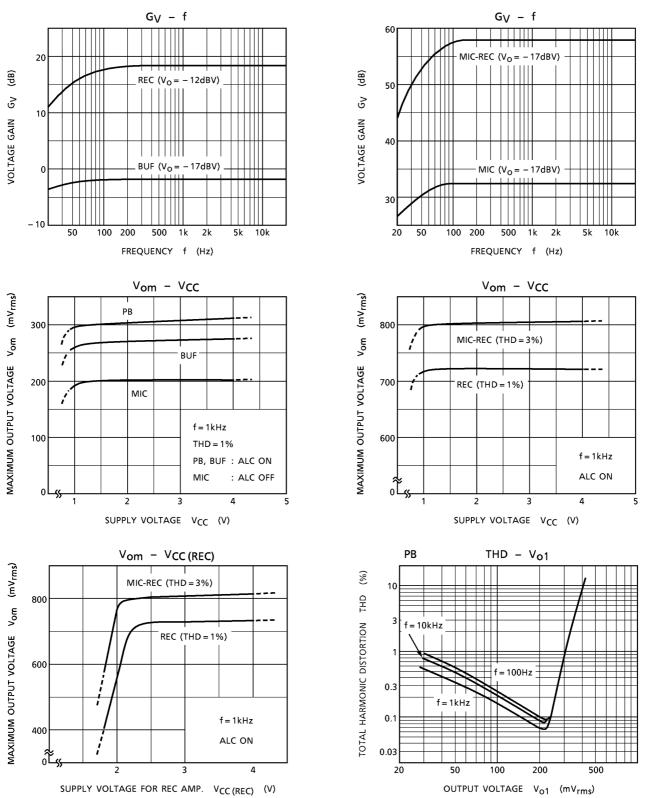
(\*) RR5 is measured by circuit below (for  $V_{CC}$  line)



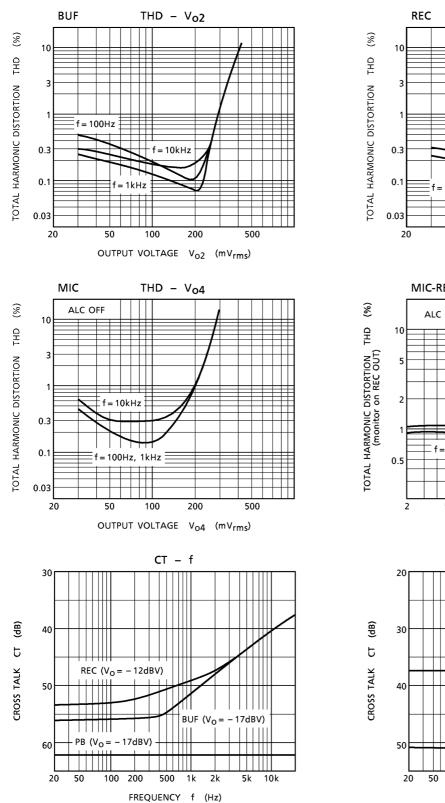
#### Characteristic Curves Unless Otherwise Specified

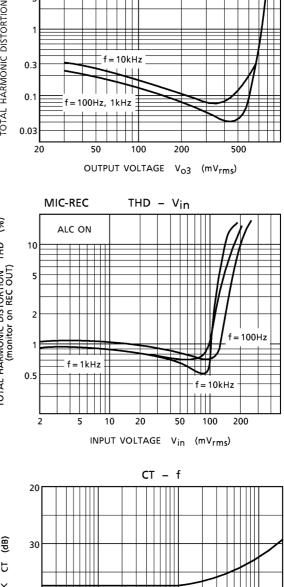
 $V_{CC}$  = 1.2V,  $V_{CC(REC)}$  = 2.4V, f = 1kHz, Ta = 25°C R<sub>L</sub> = 10k $\Omega$  : PB amp., BUF amp., MIC amp. (load of recoading amplifier is shown in test circuit)





THD - Vo3





MIC-REC ( $V_{in} = -32 dBV$ )

500 1k 2k

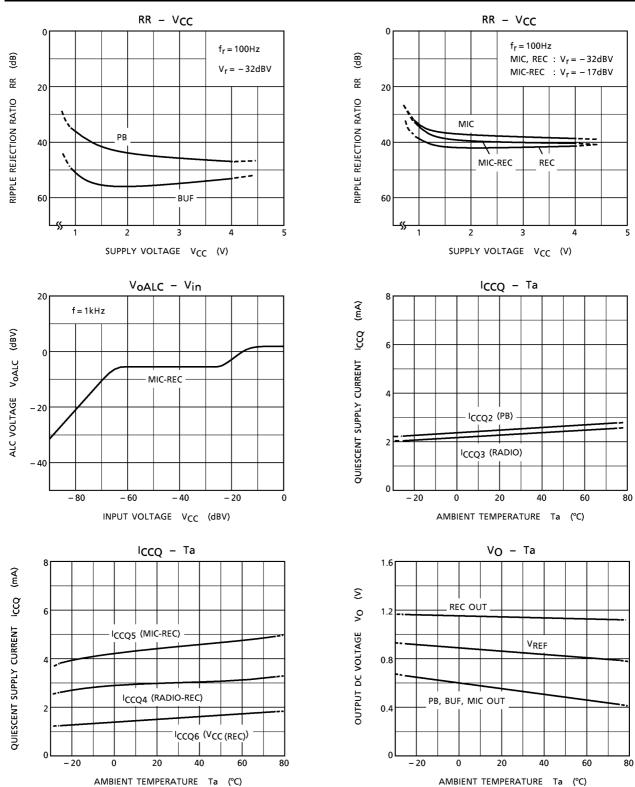
FREQUENCY f (Hz)

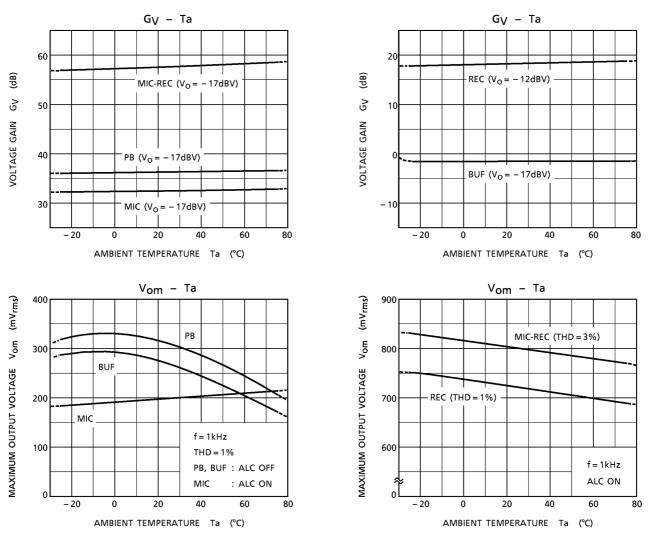
MIC ( $V_0 = -17 dBV$ )

100 200

5k 10k

## <u>TOSHIBA</u>

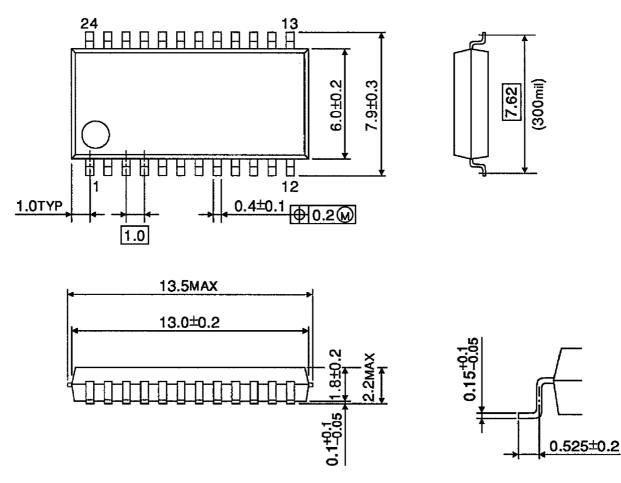




### Package Dimensions

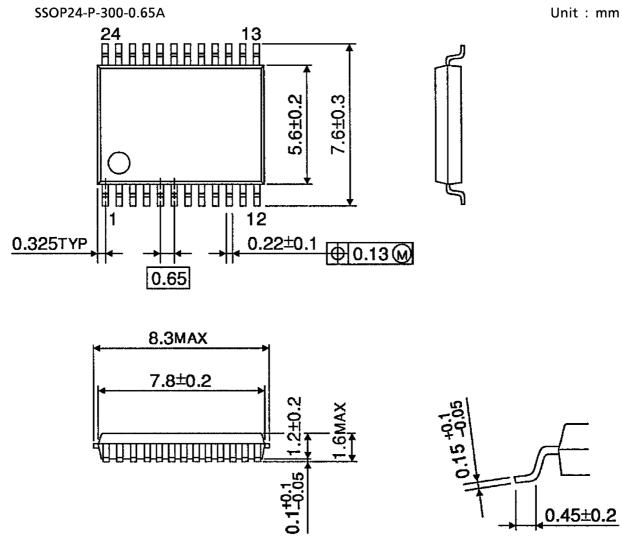
SSOP24-P-300-1.00

Unit : mm



Weight: 0.32g (typ.)

#### **Package Dimensions**



Weight: 0.14g (typ.)

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